TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SP57FU, TC7SP58FU

Low Voltage Single Configurable Multiple Function Gate with 3.6-V Tolerant Inputs and Outputs

The TC7SP57,58 is a high performance CMOS multiple Function Gate which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5 V, 1.8 V, 2.5 V or 3.3 V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

It is also designed with over voltage tolerant inputs and outputs up to 3.6 V.

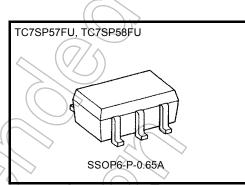
The output state is determined by seven patterns of 3-inputs.

The user can choose the functions of

XNOR(TC7SP57), XOR(TC7SP58), AND, OR, NAND, NOR,

Schmitt Inverter, and Schmitt Buffer.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.0068 g (typ)

#### **Features**

Low-voltage operation:  $V_{CC} = 1.2 \text{ to } 3.6 \text{ V}$ 

High-speed operation:  $t_{pd} = 8.5 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$ 

 $t_{pd} = 12.0 \text{ ns (max) (V}_{CC} = 2.3 \text{ to } 2.7 \text{ V})$ 

 $|I_{OH}| / I_{OL} = 8 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$ Output current:

 $|I_{OH}| / I_{OL} = 4 \text{ mA (min) (VCC} = 2.3 \text{ V)}$ 

 $|I_{OH}| / I_{OL} = 1.5 \text{ mA (min) (V}_{CC} = 1.65 \text{ V})$ 

-300 mA Latch-up performance:

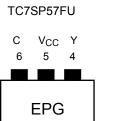
Machine model > ±200 V ESD performance:

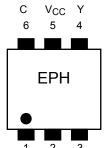
Human body model  $> \pm 2000 \text{ V}$ 

Package:

Power-down protection is provided on all inputs and outputs

## Pin Assignment (top view)





B GND A

TC7SP58FU

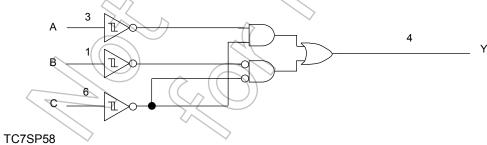


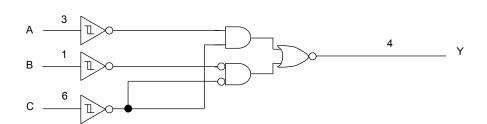
B GND A

	INPUTS		OUTPUT			
	INFOIS	•	TC7SP57	TC7SP58		
Α	В	С	Y	Y		
L	L	L	Н	L		
L	L	Н	L	Н		
L	Н	L	Н	L ((		
L	Н	Н	Н	L		
Н	L	L	L	(H \		
Н	L	Н	L			
Н	Н	L	L (	(// <del>(</del> f)		
Н	Н	Н	H			









# Logic configrations(1/2)

Function	Input Condition	TC7SP57 Logic symbol	TC7SP58 Logic symbol	Function Table
0057	Jonation	Logio symbol	Logio symbol	TUDIC
SP57 Schmitt AND or Schmitt INV + NOR  SP58 Schmitt NAND or Schmitt INV + OR	A=H-Level B=INPUT C=INPUT Y=OUTPUT	B OR OR C Y	B Y OR Y C J Y	A B C Y 57 58 H L L L H H H L H H H L H H H L L H
SP57 Schmitt INV +NAND or Schmitt INV +OR SP58 Schmitt INV +AND or Schmitt INV + AND	A=L-Level B=INPUT C=INPUT Y=OUTPUT	B OR Y OR B C TY	B OF Y  B OF Y	A B C Y 57 58 L L L L H L L L H L L L H L L L H L L L L H L
SP57 Schmitt INV +NAND or Schmitt INV + OR  SP58 Schmitt INV +AND or Schmitt INV + AND	A= INPUT B= H-Level C=INPUT Y=OUTPUT	A C OR Y	A C OR Y	A B C Y 57 58 L H L H L L H H L H H L H H L L
SP57 Schmitt INV +AND or Schmitt INV +NOR SP58 Schmitt INV + NAND or Schmitt INV + OR	A=INPUT B=L-Level C=INPUT Y=OUTPUT	A OF Y  OR  A  C  OF  Y	A Y C OR OR C Y	A B C Y 57 58 L L L H L L L H L H H L L L H H L H
SP57 Schmitt XNOR  SP58 Schmitt XOR	A=B B=INPUT C=INPUT Y=OUTPUT	B C Y	B Y	A B C Y 57 58 L L L H L L L H L H H H L L H H H H L L H

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# Logic configrations(2/2)

Function	Input	TC7SP57	TC7SP58	Function
	Condition	Logic symbol	Logic symbol	Table
SP57 Schmitt INV	A= INPUT B=L-Level			A B C Y 57 58
SP58 Schmitt Buffer	C=L-Level Y=OUTPUT	A Y	A Y	L
SP57 Schmitt INV	A= INPUT B=H-Level			A B C Y 57 58
SP58 Schmitt Buffer	C=L-Level Y=OUTPUT	A — Y	A	L H L H L H H H H H H H L H
SP57 Schmitt Buffer	A=L-Level B= INPUT			A B C Y 58
SP58 Schmitt INV	C=H-Level Y=OUTPUT	В Y	B Y	L L H H L L
SP57 Schmitt Buffer	A=H-Level B=INPUT			A B C Y 57 58
SP58 Schmitt INV	C=H-Level Y=OUTPUT	B Y	B Z	H L H L H

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#### **Absolute Maximum Rating (Note1)**

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V <sub>CC</sub>	-0.5 to 4.6	V	
DC input voltage	V <sub>IN</sub>	-0.5 to 4.6	V	
		-0.5 to 4.6 (Note2)	V	
DC output voltage	Vout	-0.5 to V <sub>CC</sub> + 0.5 (Note3)		
Input diode current	I <sub>IK</sub>	-20	mA	
Output diode current	lok	±20 (Note4)	mA (/	
DC output current	lout	±25	mA	
Power dissipation	PD	180	mW	
DC V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>	±25	mA	
Storage temperature	T <sub>stg</sub>	-65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2:  $V_{CC} = 0 V$ 

Note 3: High or Low state. IOUT absolute ratingmust be observed.

Note 4:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$ 

## **Operating Ranges (Note1)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	1.2 to 3.6	V	
Input voltage	V <sub>IN</sub>	-0.3 to 3.6	٧	
Output voltage	Vout	0 to 3.6 (Note2)	V	
Output voltage		0 to V <sub>CC</sub> (Note3)		
	$\wedge$	±8.0 (Note4)		
Output current	IOH/IOL	±4.0 (Note5)	mA	
		±1.5 (Note6)	ļ	
Operating temperature	Topr	-40 to 85	°C	

Note 1: The operating range is required to ensure the normal operation of the device. Unused inputs must be tied to either V<sub>CC</sub> or GND.

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Note 2:  $V_{CC} = 0 V$ 

Note 3: High or low state

Note 4:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 5:  $V_{CC} = 2.3$  to 2.7 V

Note 6:  $V_{CC} = 1.65 \text{ to } 1.8 \text{ V}$ 



### **Electrical Characteristics**

# DC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteris	tics	Symbol	Test Co	ndition	V 00	Min	Max	Unit
					V <sub>CC</sub> (V)		1 10	
					1.2	_	1.10	-
					1.4		1.20	
	H-level	$V_P$	_	-	1.65		1.35	V
				^	2.3	<u> </u>	1.70	-
				<	3.0	<u>)) —                                   </u>	2.00	
Input voltage					3.6	0.10	2.20	
					1.2	0.10	_	-
				$\mathcal{A}$	1.4	0.20	<del>-</del>	
	L-level	$V_N$	_	-	1.65	0.30	$\rightarrow$	V
				(770)	2.3	0.50	<u> </u>	
					3.0	(0.70)	<del></del>	
					3.6	0.80	//-	
			Α		1.2	0.2	0.9	
				1.4	0.2	0.9		
Hysteresis voltage		$V_{H}$			1.65	0.2	0.95	V
, c				2.3	0.3	1.0		
				/ [[	3.0	0.3	1.2	
					3.6	0.3	1.2	
				I <sub>OH</sub> = -100 μA	1.2 to 1.3	V <sub>CC</sub> - 0.1	_	
		(		I <sub>OH</sub> = -500 μA	1.4 to 1.6	V <sub>CC</sub> - 0.2	_	
	H-level	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -1.5 \text{ mA}$	1.65 to 1.95	V <sub>CC</sub> - 0.3	_	
		(7)	$\wedge$	$I_{OH} = -4.0 \text{ mA}$	2.3 to 2.7	V <sub>CC</sub> - 0.4	_	
Output voltage		$\setminus \setminus \setminus$	)) (	$I_{OH} = -8.0 \text{ mA}$	3.0 to 3.6	2.40	_	V
Output voltage				I <sub>OL</sub> =100 μA	1.2 to 1.3	_	0.10	ľ
				t <sub>OL</sub> = 500 μA	1.4 to 1.6		0.20	
	L-level	Vol	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 3.0 mA	1.65 to 1.95	_	0.25	
	$\nearrow$			I <sub>OL</sub> = 4.0 mA	2.3 to 2.7	_	0.40	
2			$\wedge$	I <sub>OL</sub> = 8.0 mA	3.0 to 3.6	_	0.40	
Input leakage current I <sub>IN</sub>		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		1.2 to 3.6	_	±1.5	μА
Power-off leakage current IOFF		V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0	_	1.5	μА	
Quiescent supply current		V <sub>IN</sub> = V <sub>CC</sub> or GND		1.2 to 3.6	_	3.0		
		ICC	V <sub>CC</sub> ≤ V <sub>IN</sub> ≤ 3.6 V		1.2 to 3.6	_	±3.0	μА
Increase in I <sub>CC</sub> per i	nput	Δlcc	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V		2.7 to 3.6	_	100	1

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### AC Characteristics (Ta = -40 to $85^{\circ}$ C, Input: $t_r = t_f = 3.0$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
	4	Figure 4 Figure 2	1.8± 0.15	1.0	21.0	
	t <sub>pLH</sub>	Figure 1, Figure 2 $CL = 10pF, R_L = 1 M\Omega$	2.5 ± 0.2	0.8	10.0	ns
	t <sub>pHL</sub>		3.3 ± 0.3	0.6	7.0	
Propagation delay time	t <sub>pLH</sub> t <sub>pHL</sub> t <sub>pLH</sub> t <sub>pHL</sub>	Figure 1, Figure 2 $CL = 15pF, R_L = 1 M\Omega$	1.8± 0.15	1.0	23.0	
(A, B,C-Y)			2.5 ± 0.2	0.8	11.0	ns
(A, D,O-1)			3.3 ± 0.3	0.6	7.7	
		Figure 1 Figure 2	1.8± 0.15	1.0	27.0	
		Figure 1, Figure 2 $CL = 30pF$ , $R_L = 1 M\Omega$	$2.5\pm0.2$	0.8	12.0	ns
		OL - 3001 (11L - 1 19152	$3.3 \pm 0.3$	0.6	8.5	

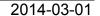
### **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Vec (V)	Typ.	Unit
Input capacitance	C <sub>IN</sub>		1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz	(Note) 1.8, 2.5, 3.3	30	pF

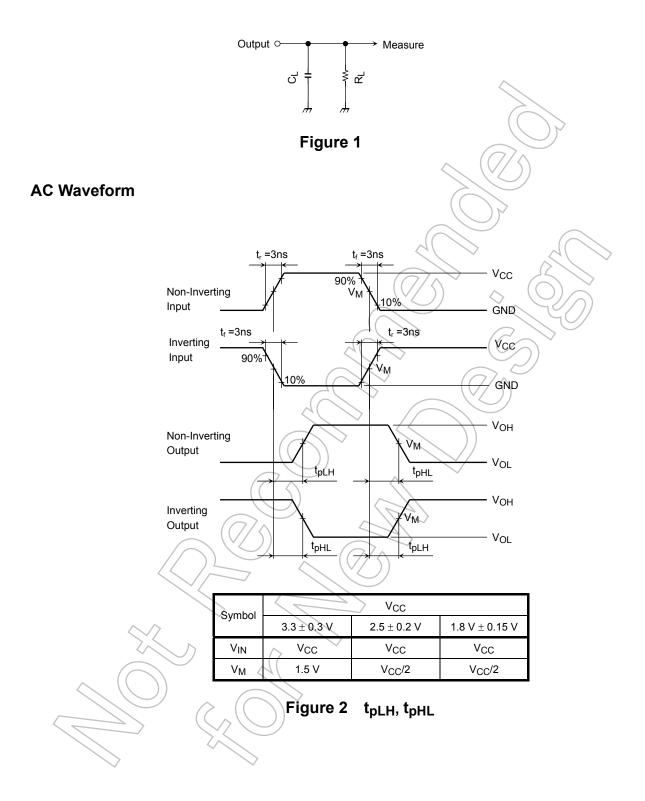
Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

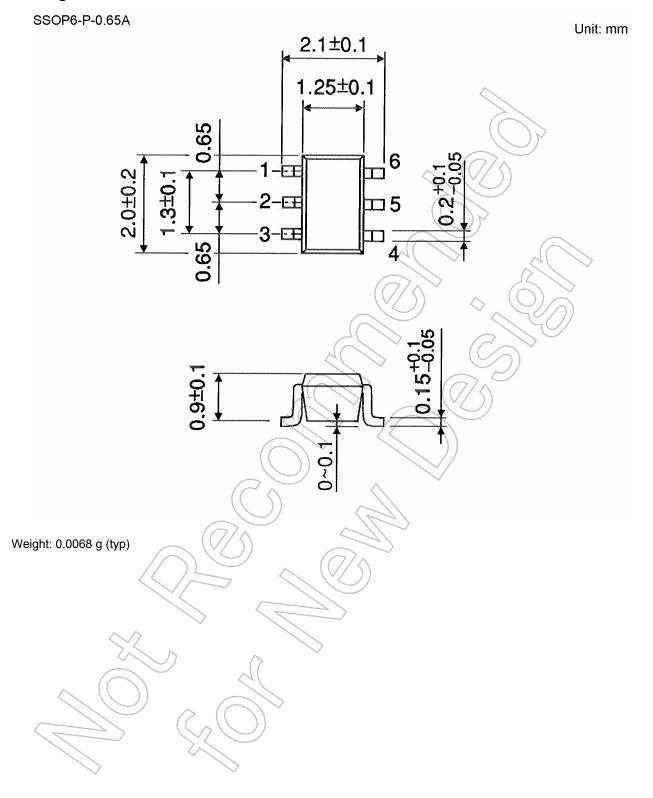


#### **AC Test Circuit**





## **Package Dimensions**



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